

Symbol	Parameter	Ratings	Units		
V _{DSS}	Drain-to-Source Voltage		40	V	
V _{GS}	Gate-to-Source Voltage		±20	V	
I _D	Drain Current - Continuous (V _{GS} =10) (Note 1)	T _C =25°C	240	Α	
	Pulsed Drain Current	T _C = 25°C	See Figure 4		
E _{AS}	Single Pulse Avalanche Energy	(Note 2)	737	mJ	
P _D	Power Dissipation		357	W	
	Derate Above 25°C		2.38	W/ºC	
T _J , T _{STG}	Operating and Storage Temperature		-55 to + 175	°C	
$R_{\theta JC}$	Thermal Resistance, Junction to Case		0.42	°C/W	
$R_{\theta JA}$	Maximum Thermal Resistance, Junction to Ambient	(Note 3)	43	°C/W	

Notes:

1: Current is limited by bondwire configuration.

2: Starting $T_J = 25^{\circ}$ C, L = 0.36mH, $I_{AS} = 64A$, $V_{DD} = 40V$ during inductor charging and $V_{DD} = 0V$ during time in avalanche.

3: R_{0JA} is the sum of the junction-to-case and case-to-ambient thermal resistance, where the case thermal reference is defined as the solder mounting surface of the drain pins. R_{0JC} is guaranteed by design, while R_{0JA} is determined by the board design. The maximum rating presented here is based on mounting on a 1 in² pad of 2oz copper.

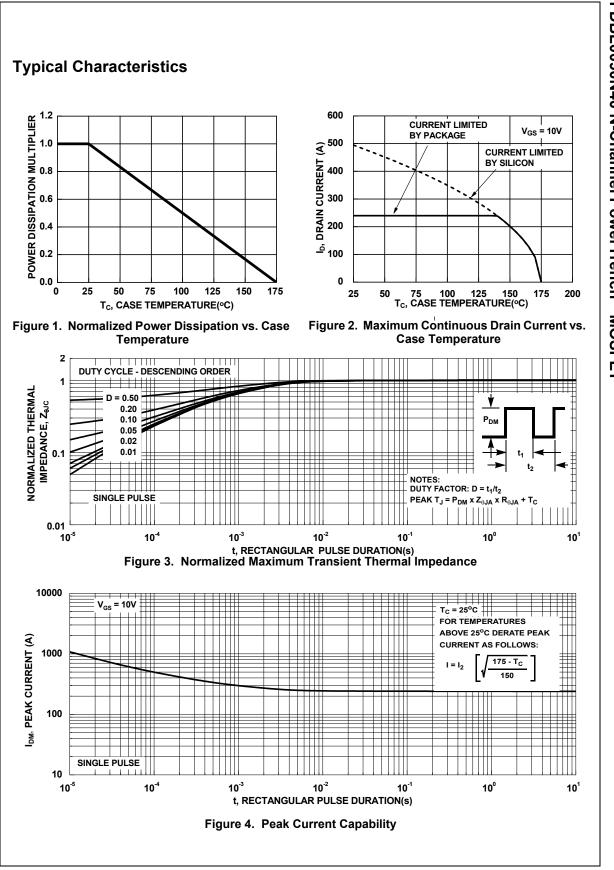
Package Marking and Ordering Information

Device Marking	Device	Package			
FDBL0090N40	FDBL0090N40	MO-299A	-	-	-

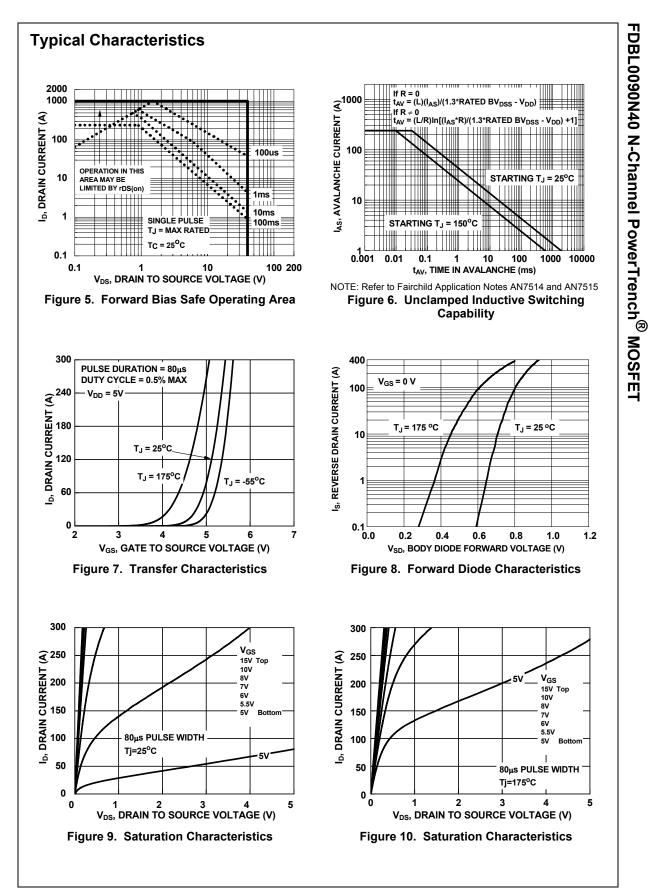
Symbol	Parameter	Test Conditions		Min.	Тур.	Max.	Units
-	racteristics		I		,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,		
B _{VDSS}	Drain-to-Source Breakdown Voltage	I _D = 250μA, V _{GS} = 0V		40	-	-	V
		V _{DS} =40V, T _J = 25 ^o C		-	-	1	μA
IDSS	Drain-to-Source Leakage Current	$V_{GS} = 0V$ $T_J = 175^{\circ}O$	C (Note 4)	-	-	1	mA
I _{GSS}	Gate-to-Source Leakage Current	$V_{GS} = \pm 20V$		-	-	±100	nA
On Cha	racteristics			-			
V _{GS(th)}	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_D = 250 \mu A$		2.0	3.3	4.0	V
	Drain to Source On Resistance	$I_{\rm D} = 80$ A, $T_{\rm J} = 25^{\circ}$ C		-	0.65	0.90	mΩ
R _{DS(on)}	Drain to Source On Resistance	V_{GS} = 10V T _J = 175 ^o	C (Note 4)	-	1.10	1.50	mΩ
C _{iss}	C Characteristics	V _{DS} = 25V, V _{GS} = 0V, f = 1MHz f = 1MHz		-	12000	_	pF
C _{oss}	Output Capacitance			-	3260	-	, pF
C _{rss}	Reverse Transfer Capacitance			-	442	-	pF
R _q	Gate Resistance			-	3.3	-	Ω
Q _{g(ToT)}	Total Gate Charge at 10V	V_{GS} = 0 to 10V V_{DD} = 32V		-	144	188	nC
Q _{g(th)}	Threshold Gate Charge	$V_{GS} = 0 \text{ to } 2V$ I_D			22	26	nC
Q _{gs}	Gate-to-Source Gate Charge	-		-	66	-	nC
Q _{gd}	Gate-to-Drain "Miller" Charge			-	16	-	nC
Switchi	ng Characteristics						
t _{on}	Turn-On Time	V _{DD} = 20V, I _D = 80A,		-	-	162	ns
t _{d(on)}	Turn-On Delay			-	42	-	ns
t _r	Rise Time			-	73	-	ns
t _{d(off)}	Turn-Off Delay	V _{GS} = 10V, R _{GEN} = 6Ω	-	-	83	-	ns
t _f	Fall Time			-	50	-	ns
t _{off}	Turn-Off Time			-	-	279	ns
Drain-S	ource Diode Characteristics						
	Source-to-Drain Diado Voltago	I _{SD} =80A, V _{GS} = 0V		-	-	1.25	V
V _{SD}	Source-to-Drain Diode Voltage	I_{SD} = 40A, V_{GS} = 0V		-	-	1.2	V
t _{rr}	Reverse-Recovery Time	$I_{F} = 80A, dI_{SD}/dt = 100$	A/μs,	-	111	129	ns
	Reverse-Recovery Charge	V _{DD} =32V		-	178	214	nC

Note:

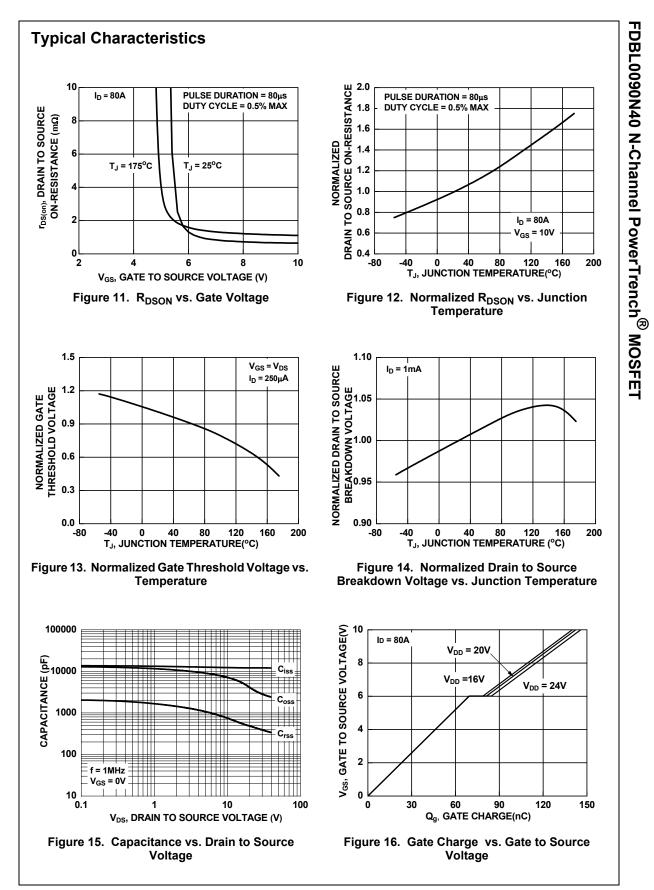
4: The maximum value is specified by design at T_J = 175°C. Product is not tested to this condition in production.



FDBL0090N40 N-Channel PowerTrench[®] MOSFET



FDBL0090N40 Rev.C2



FDBL0090N40 Rev.C2



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